



ocket No.: 50099-180

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Shigenobu MAEDA, et al.

Application No.: 09/988,593

Filed: November 20, 2001

Group Art Unit: 2823

Examiner: T. Pham

For: SEMICONDUCTOR DEVICE HAVING IMPURITY REGION UNDER ISOLATION
REGION (As amended)

#8/a
3/14/13
Surber

AMENDMENT

Box Non-Fee Amendment
The Commissioner for Patents and Trademarks
Washington, DC 20231

Sir:

The following Amendment and Remarks are submitted in response to the Office Action
dated December 13, 2002. Please amend the above-identified application as follows:

IN THE TITLE:

Please replace "SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING
THE SAME" with --SEMICONDUCTOR DEVICE HAVING IMPURITY REGION UNDER
ISOLATION REGION--.

IN THE SPECIFICATION:

Please delete the first two full paragraphs in page 21 in their entirety and replace with the
following:

RECEIVED
MAR 12 2003
TECHNOLOGY CENTER 2800